

### KSC5803

# High Voltage Color Display Horizontal Deflection Output (No Damper Diode)

- High Breakdown Voltage : BV<sub>CBO</sub>=1500V
- High Speed Switching: t<sub>F</sub>=0.1μs (Typ.)
- Wide S.O.A
- For C-Monitor(85KHz)



### **NPN Triple Diffused Planar Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	1500	V
V <sub>CEO</sub>	Collector-Emitter Voltage	800	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
I <sub>C</sub>	Collector Current (DC)	12	А
I <sub>CP</sub>	Collector Current (Pulse)	24	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	70	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CES</sub>	Collector Cut-off Current	$V_{CE} = 1400V, V_{BE} = 0$			1	mA
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CE} = 800V, I_{E} = 0$			10	μА
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$			1	mA
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 1A$	15		40	
h <sub>FE2</sub>	32	$V_{CE} = 5V, I_{C} = 8A$	5.5		8.5	_ =
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 8A, I_B = 2A$			3	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 8A, I_B = 2A$	110	- 53	1.5	V
t <sub>STG</sub>	Storage Time	V <sub>CC</sub> = 200V, I <sub>C</sub> = 7A			4	μs
t <sub>F</sub>	Fall Time	$I_{B1} = 1.4A, I_{B2} = -2.8A$ $R_L = 28.6\Omega$	4	M. All A.	0.3	μs

# **Typical Characteristics**

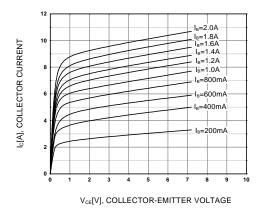


Figure 1. Static Characteristic

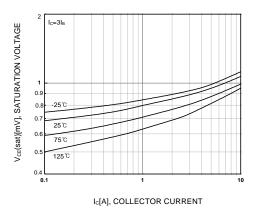


Figure 3. Base-Emitter Saturation Voltage

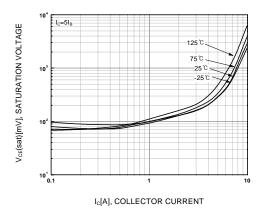


Figure 5. Collector-Emitter Saturation Voltage 2

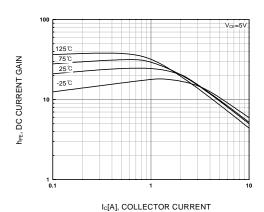


Figure 2. DC current Gain

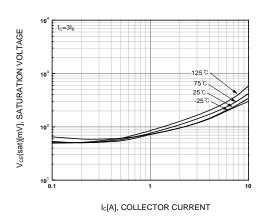


Figure 4. Collector-Emitter Saturation Voltage 1

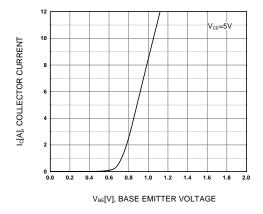


Figure 6. Base-Emitter On Voltage

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# **Typical Characteristics** (Continued)

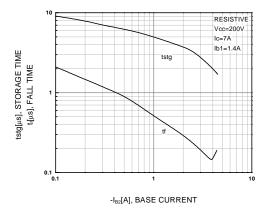


Figure 7. Switching Time

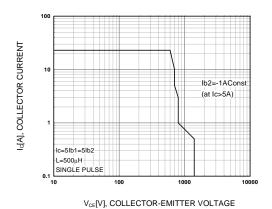


Figure 9. Reverse Bias Safe Operating Area

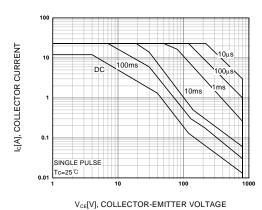


Figure 8. Safe Operating Area

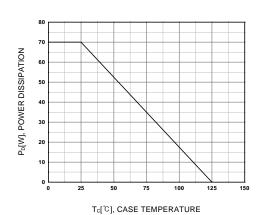
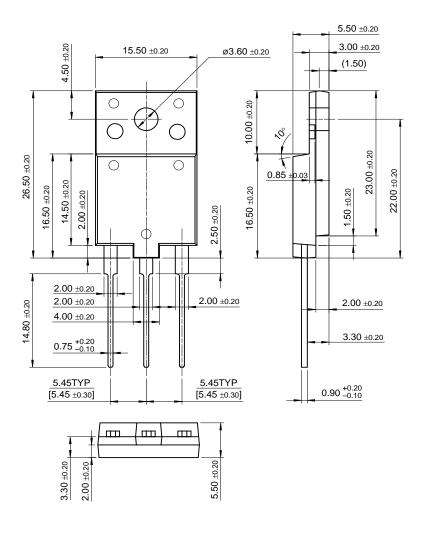


Figure 10. Power Derating

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# **Package Demensions**

# TO-3PF



Dimensions in Millimeters

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